Overvoltage Transient Suppressor

...designed for applications requiring a diode with reverse avalanche characteristics for use as reverse power transient suppressor.

Developed to suppress transients in the automotive system, this device operates in reverse mode as power zener diode and will protect expensive modules such as ignition, injection and autoblocking systems from overvoltage conditions.

- High Power Capability
- Economical

Mechanical Characteristics

- Finish: All External Surfaces are Corrosion Resistant
- Polarity: Cathode to Terminal
- Weight: 1.78 Grams (Approximately)
- Maximum Temperature for Soldering Purposes: 260°C for 10 s using a Belt Furnace
- Marking: MR2835S

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
DC Blocking Voltage	V _R	23	V
Peak Repetitive Reverse Surge Current (Time Constant = 10 ms, T _C = 25°C)	I _{RSM}	I _{RSM} 62	
Non-Repetitive Peak Surge Current (Half-wave, Single Phase, 50 Hz)	I _{FSM}	400	Α
Storage Temperature Range	T _{stg}	-40 to +150	°C
Operating Junction Temperature Range	TJ	-40 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.0	°C/W

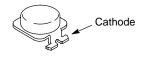
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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MARKING DIAGRAM





TOP CAN BUTTON CASE 460

= Lot Number

MR2835S = Specific Device Code

YY = Year WW = Work Week

ORDERING INFORMATION

Device	Device Package Ship	
MR2835SK	Top Can Button	500/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Instantaneous Forward Voltage (I _F = 100 A) (Note 1)	V _F	-	1.1	Volts
Reverse Current (V _R = 20 V) (Note 1)	I _R	-	5.0	μΑ
Breakdown Voltage (I _Z = 100 mA) (Note 1)	V _(BR)	24	32	Volts
Breakdown Voltage (I _Z = 80 A, T _C = 85°C, PW = 80 μs)	V _(BR)	-	40	Volts
Breakdown Voltage Temperature Coefficient	V _{(BR)TC}	-	0.09	%/°C
Forward Voltage Temperature Coefficient (I _F = 10 mA)	V _{FTC}	-	-2.0*	mV/°C

^{1.} Pulse Test: Pulse Width < 300 $\mu\text{s},$ Duty Cycle < 2%.

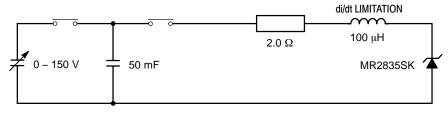


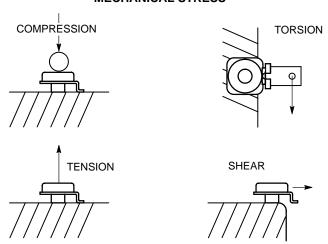
Figure 1. Load Dump Test Circuit

MOUNTING AND HANDLING

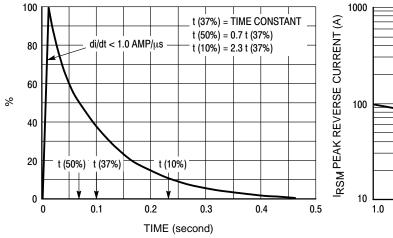
The mechanical stress limits for the Top Can diode are as follows:

Compression:33.7 lbs150 newtonsTension:33.7 lbs150 newtonsTorsion:6.3 inch lbs0.7 newton metersShear:56.2 lbs250 newtons

MECHANICAL STRESS



^{*}Typical



1000 TIME CONSTANT (mS)

Figure 2. Load Dump Pulse Current

Figure 3. Maximum Peak Reverse Current

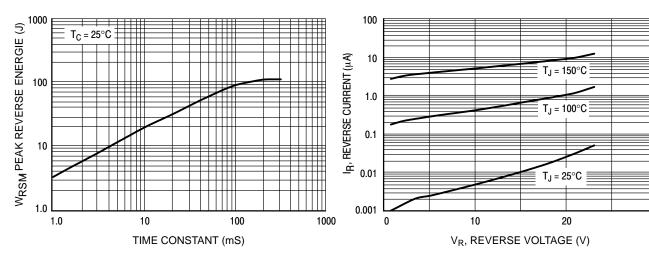


Figure 4. Maximum Reverse Energy

Figure 5. Typical Reverse Current

30

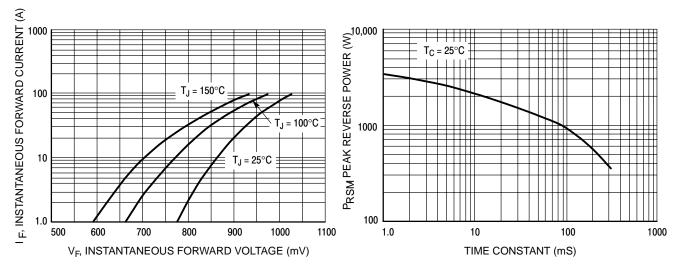


Figure 6. Typical Forward Voltage

Figure 7. Maximum Peak Reverse Power

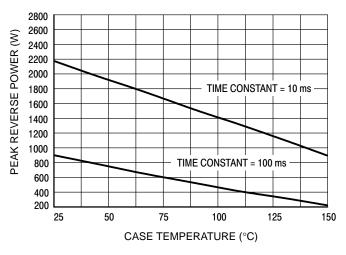


Figure 8. Reverse Power Derating

Figure 9. Typical Reverse Capacitance

Reel of 500 Units

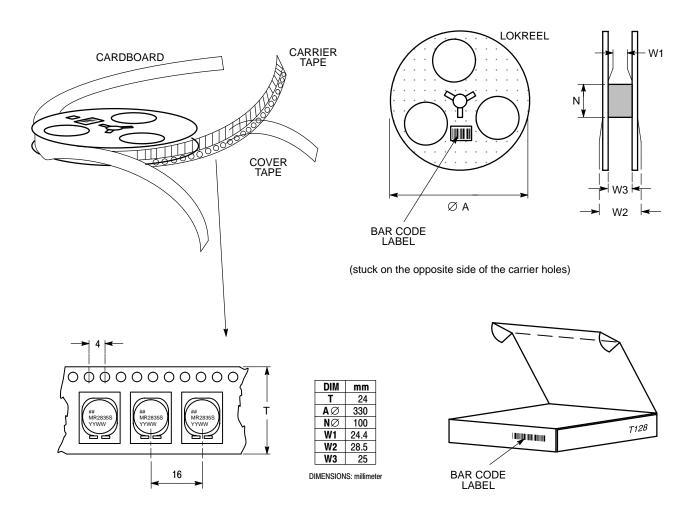
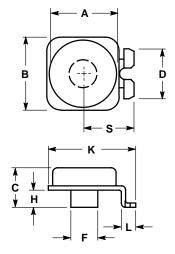


Figure 10. Reel Packing of MR2835SK - Top Can

PACKAGE DIMENSIONS

TOP CAN BUTTON

CASE 460-02 ISSUE B

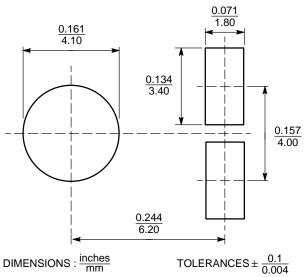


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.1	9.5	0.358	0.374	
В	9.5	9.9	0.374	0.390	
C	5.2	5.6	0.205	0.220	
D	6.4	6.8	0.252	0.268	
F	3.4	3.8	0.134	0.149	
Н	2.0	2.4	0.079	0.095	
K	11.4	11.8	0.449	0.465	
L	1.8	2.2	0.071	0.087	
S	6.5	6.9	0.256	0.272	

FOOTPRINT

Minimum circuit board footprint for Top Can Diode in Case 460-02



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